

Microfluidic thermal management of components

for High Energy Physics and Space Applications

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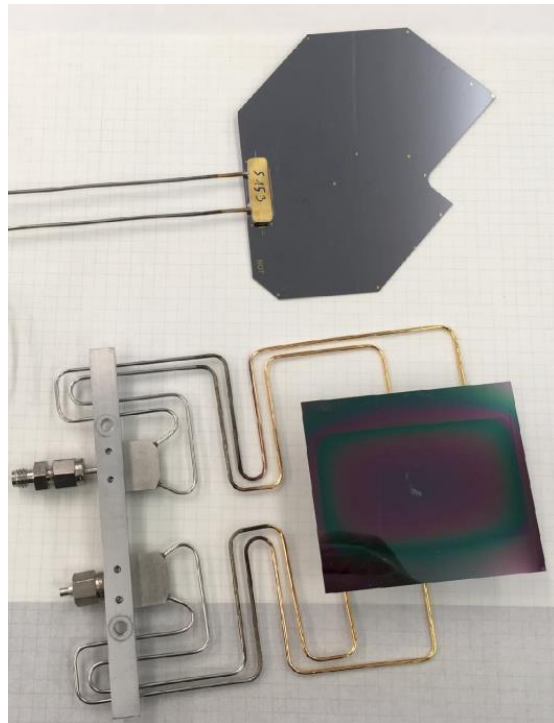
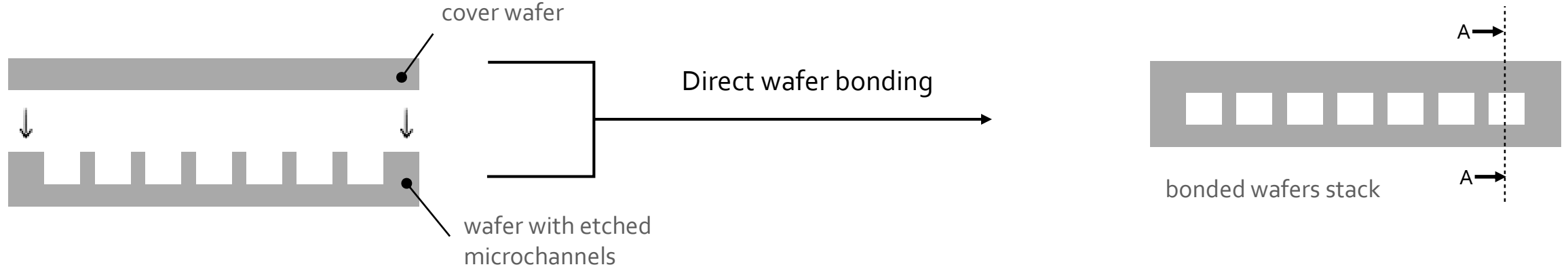


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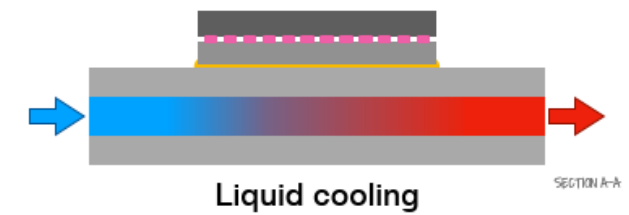
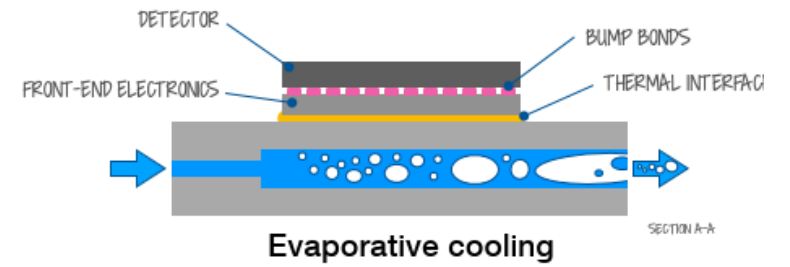
^c EPFL, Lausanne, 1015, Switzerland

Silicon microfluidic cold plates



LHCb VeLo

NA62



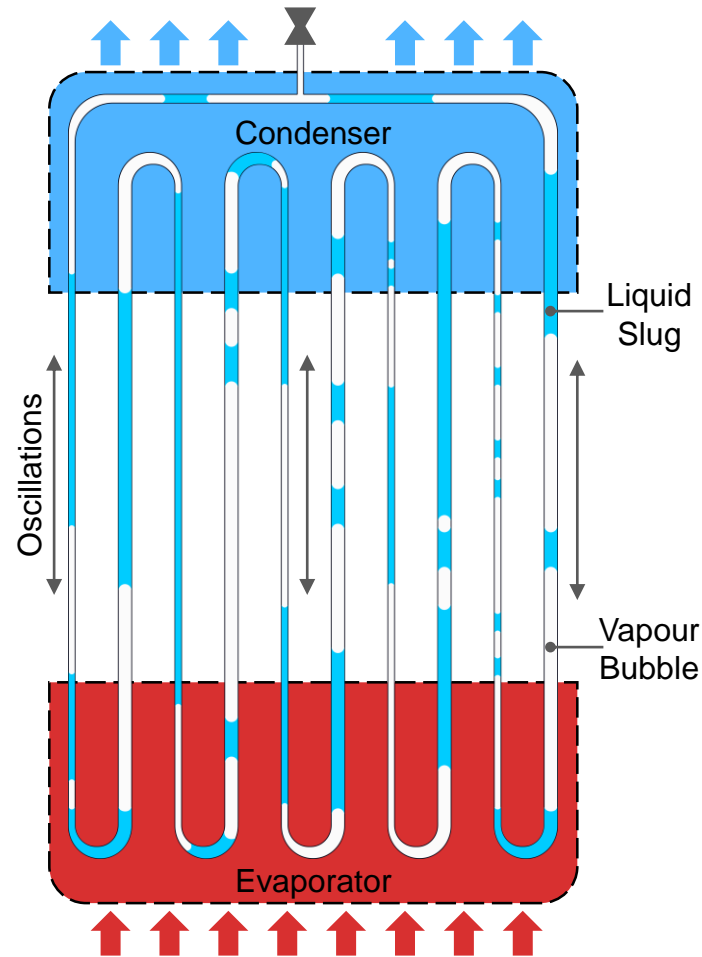
Silicon-based micro oscillating heat pipe (μ OHP)

Principle of operation

- Multiple turns channel
- No wick structure
- Partially filled
- Change of fluid's state drives the fluid motion
- Highly chaotic and unstable two phase flow.

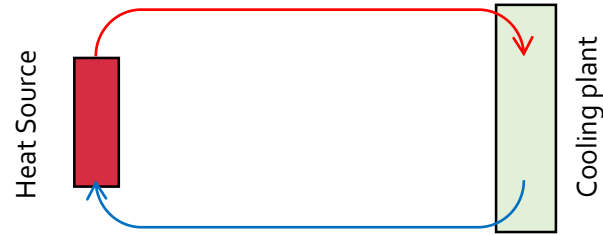
Advantages

- High thermal conductivity
- Self-actuating / passive
- Micro-fabricated (reduced thickness)



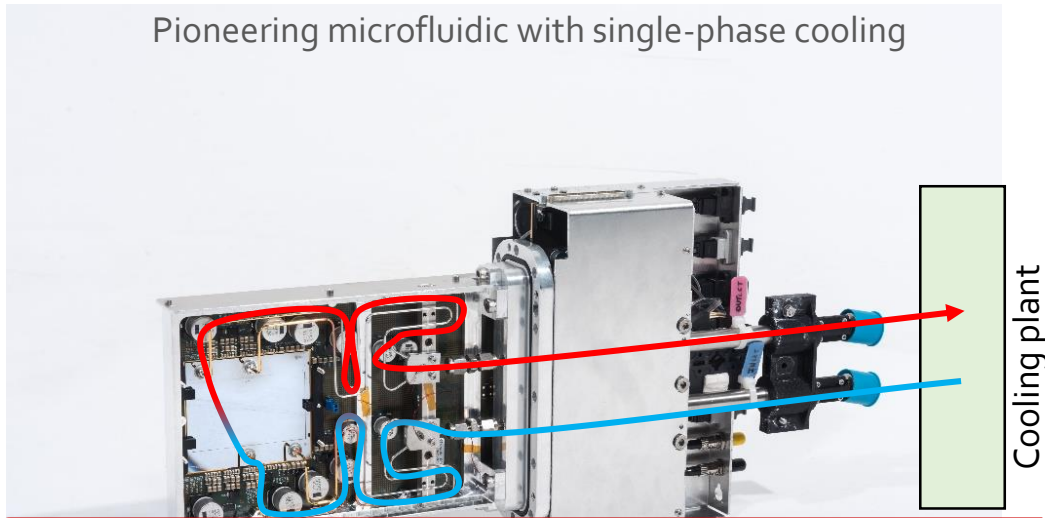
From a single cooling circuit to two cooling circuits

Common approach : single cooling circuit



NA62 module

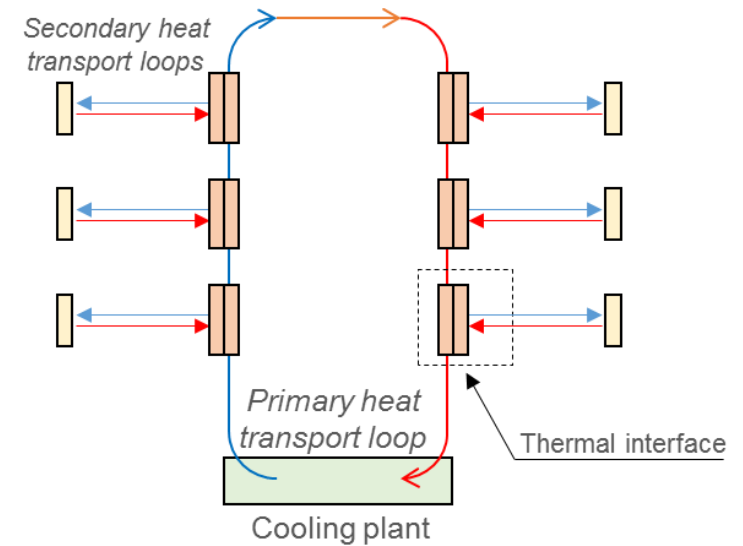
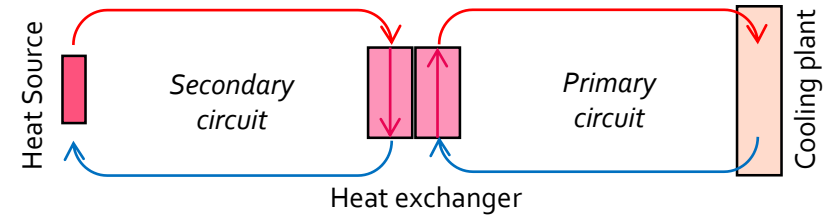
Pioneering microfluidic with single-phase cooling



Challenging fluidic interconnection
(material budget, joining technique, reliability)

Decoupling the fluidic interface by creating two cooling loops:

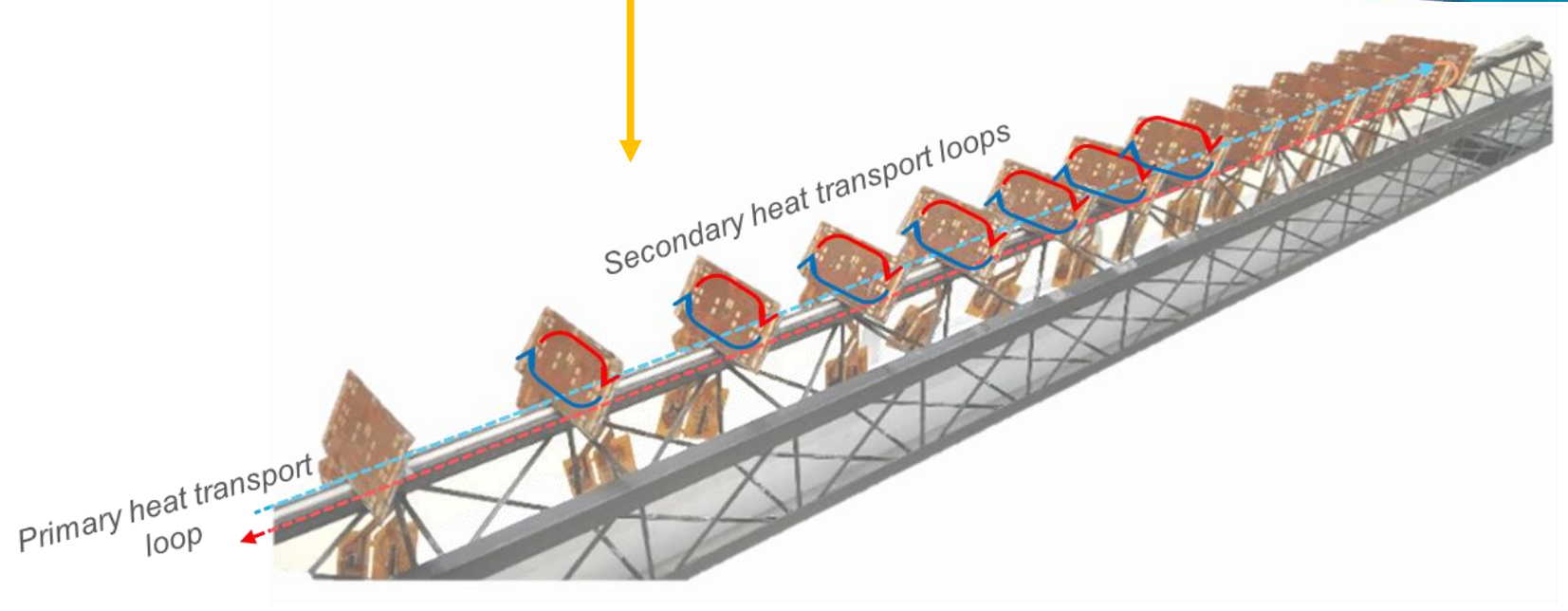
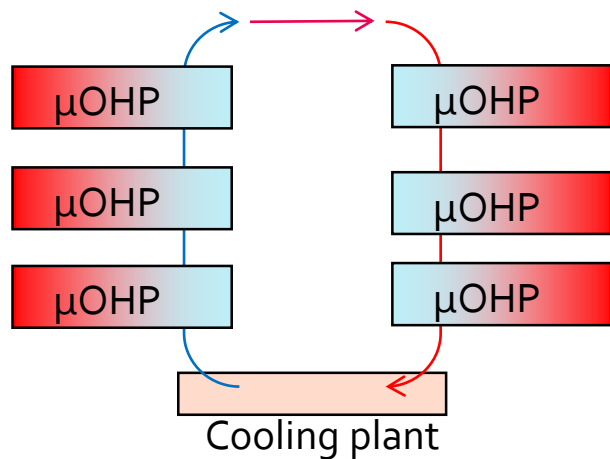
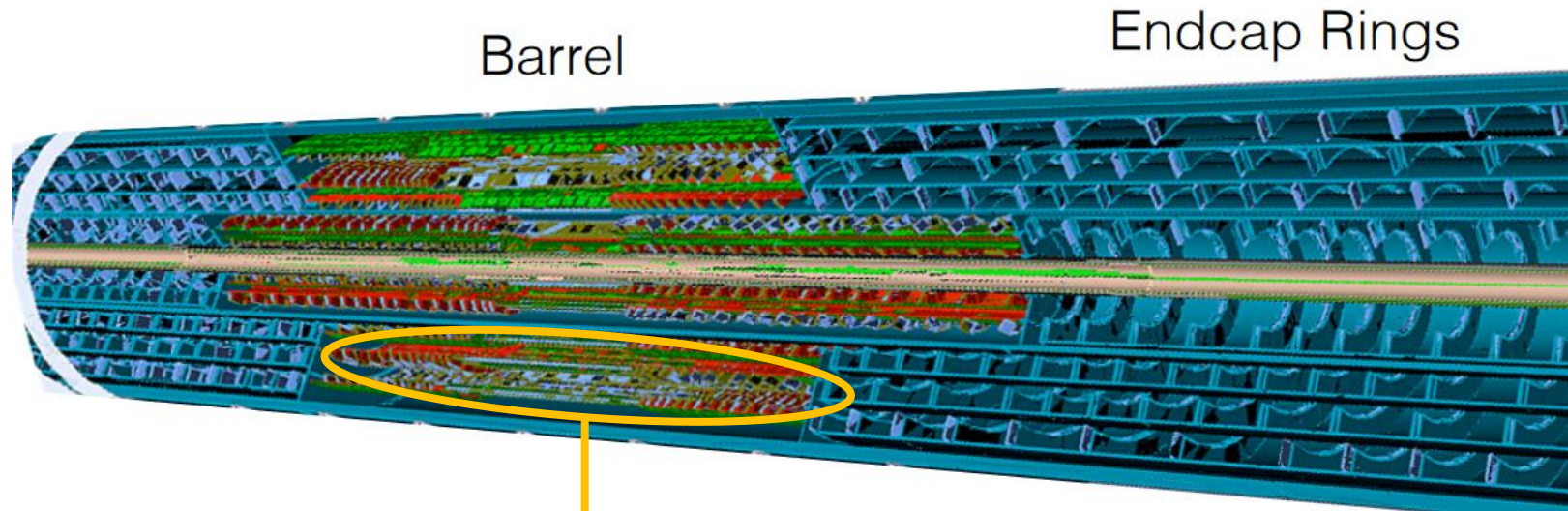
- Two fluidically independent cooling loops
- Mechanical and thermal interfaces only (re-workable)



Case study in HEP: ATLAS ITk Outer Barrel stave

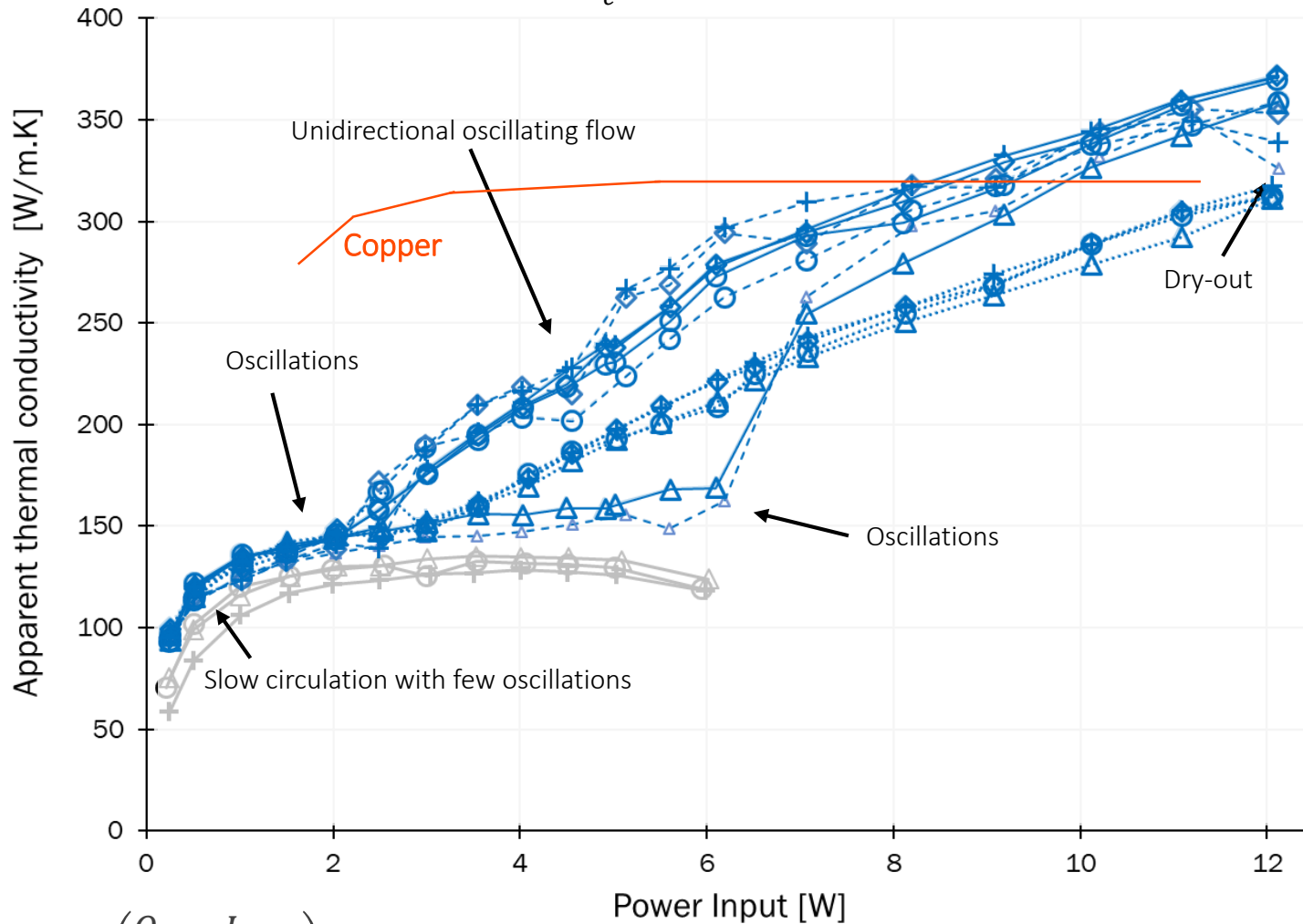
Integration on the backside of the silicon sensors

- Reduced thermal path
- Easier integration

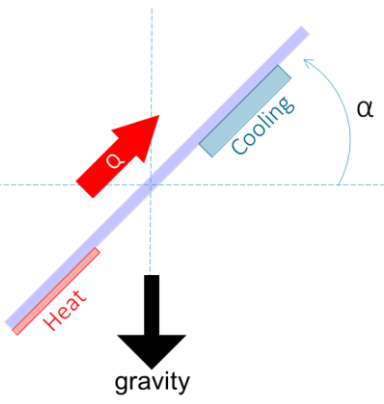


Thermal Performance of the device

$T_c = 20^\circ\text{C}$



- △- Acetone (35%) -90° (top heating mode)
- Acetone (35%) 0°
- ◇- Acetone (35%) 45°
- +- Acetone (35%) 90° (bottom heating mode)
- △ Acetone (50%) -90° (top heating mode)
- Acetone (50%) 0°
- ◇ Acetone (50%) 45°
- + Acetone (50%) 90° (bottom heating mode)
- △ Acetone (75%) -90° (top heating mode)
- Acetone (75%) 0°
- ◇ Acetone (75%) 45°
- + Acetone (75%) 90° (bottom heating mode)
- uOHP (0%) 0°
- + uOHP (0%) 90° (bottom heating mode)
- △ uOHP (0%) -90° (top heating mode)



Dimensions
 LOA: 60mm
 L: 35mm
 W: 20mm
 t: 1.1mm
 w₁ : 400um
 w₂ : 225um
 d: 400um

$$k_{app} = \left(\frac{Q}{A} \frac{L}{(T_h - T_c)} \right)$$

- Up to 535 W/m.K (9W , $T_c = 42^\circ\text{C}$)
- Low impact of gravity depending on liquid quantity and power input

Project partners



Knowledge
Transfer group



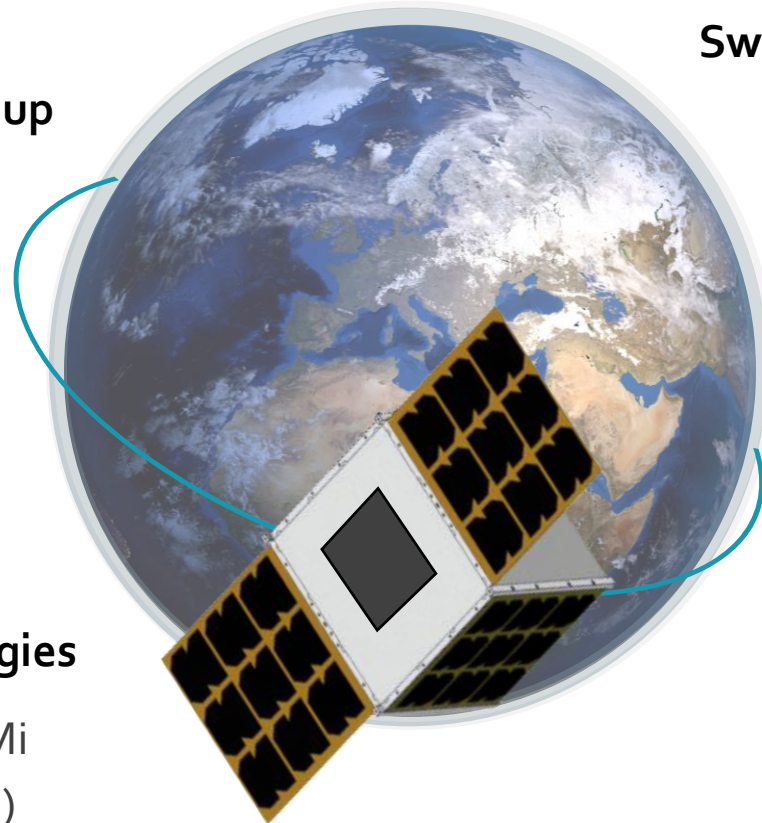
Swiss Centre of Electronics and Microtechnology

- Microfabrication expertise
- Silicon processing facilities access (6" silicon wafers processing)

The logo for EPFL, with the letters "EPFL" in a bold, red, sans-serif font.

Swiss Federal Institute of Technologies

- Strengthen link with CMI (4" silicon wafers processing)



- Promoting CERN's visibility
- Identifying space applications

Space: similar environment & similar requirements for silicon sensors and electronics

spacecenter.ch
csem.ch
home.cern
epfl.ch



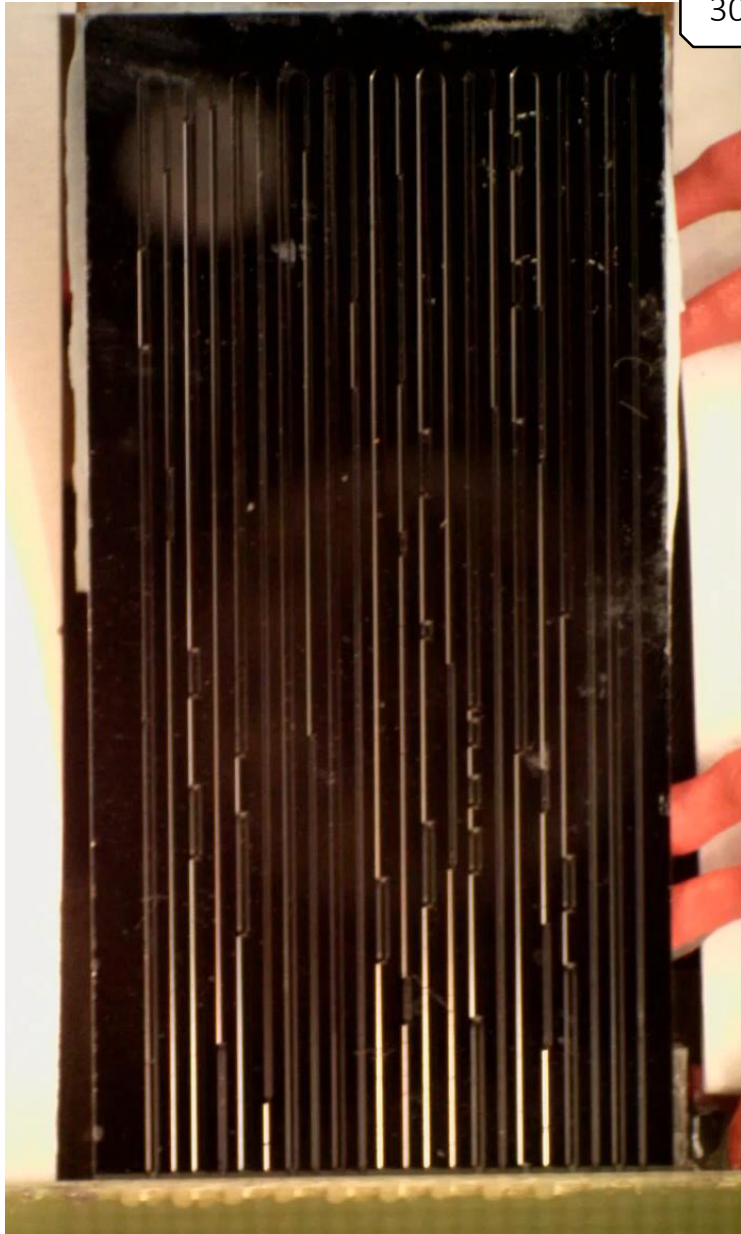
Thank you for your attention





Additional Material

First oscillations



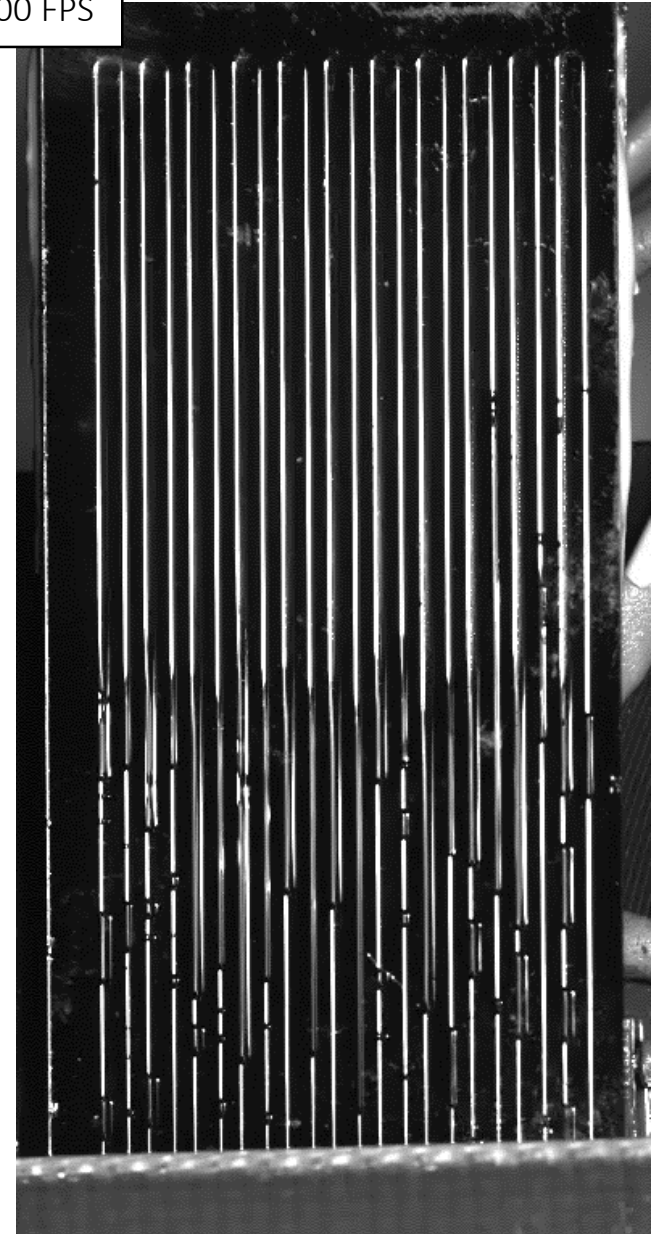
30 FPS



Heat (evaporator)



1000 FPS



Cooling (condenser)

